

PSMN027-100PS

N-channel 100V 26.8 m Ω standard level MOSFET in TO220

Rev. 3 — 12 September 2011

Product data sheet

1. Product profile

1.1 General description

Standard level N-channel MOSFET in TO220 package qualified to 175C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive

1.3 Applications

- DC-to-DC converters
- Load switching

- Motor control
- Server power supplies

1.4 Quick reference data

Table 1. Quick reference data

Parameter	Conditions	Min	Тур	Max	Unit
drain-source voltage	$T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}$	-	-	100	V
drain current	T_{mb} = 25 °C; V_{GS} = 10 V; see <u>Figure 1</u>	-	-	37	Α
total power dissipation	T _{mb} = 25 °C; see Figure 2	-	-	103	W
junction temperature		-55	-	175	°C
racteristics					
drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 15 \text{ A};$ $T_j = 100 \text{ °C}; \text{ see } \frac{\text{Figure } 12}{}$	-	-	48	mΩ
	$V_{GS} = 10 \text{ V; } I_D = 15 \text{ A;}$ $T_j = 25 \text{ °C; see } \frac{\text{Figure } 13}{\text{ Signs } 13}$	-	21	26.8	mΩ
haracteristics					
gate-drain charge	$V_{GS} = 10 \text{ V}; I_D = 30 \text{ A};$	-	9	-	nC
total gate charge	V _{DS} = 50 V; see <u>Figure 14;</u> see <u>Figure 15</u>	-	30	-	nC
ruggedness					
non-repetitive drain-source avalanche energy	$V_{GS} = 10 \text{ V; } T_{j(init)} = 25 \text{ °C;}$ $I_D = 37 \text{ A; } V_{sup} \le 100 \text{ V;}$ unclamped; $R_{GS} = 50 \Omega$	-	-	59	mJ
	drain-source voltage drain current total power dissipation junction temperature acteristics drain-source on-state resistance haracteristics gate-drain charge total gate charge ruggedness non-repetitive drain-source	$\begin{array}{lll} \text{drain-source voltage} & T_j \geq 25 \text{ °C}; \ T_j \leq 175 \text{ °C} \\ \\ \text{drain current} & T_{mb} = 25 \text{ °C}; \ V_{GS} = 10 \text{ V}; \\ \text{see } \overline{\text{Figure 1}} \\ \\ \text{total power dissipation} & T_{mb} = 25 \text{ °C}; \text{ see } \overline{\text{Figure 2}} \\ \\ \text{junction temperature} \\ \\ \text{acteristics} \\ \\ \text{drain-source on-state} & V_{GS} = 10 \text{ V}; \ I_D = 15 \text{ A}; \\ \\ T_j = 100 \text{ °C}; \text{ see } \overline{\text{Figure 12}} \\ \\ V_{GS} = 10 \text{ V}; \ I_D = 15 \text{ A}; \\ \\ T_j = 25 \text{ °C}; \text{ see } \overline{\text{Figure 13}} \\ \\ \text{haracteristics} \\ \\ \text{gate-drain charge} & V_{GS} = 10 \text{ V}; \ I_D = 30 \text{ A}; \\ \\ V_{DS} = 50 \text{ V}; \text{ see } \overline{\text{Figure 14}}; \\ \\ \text{see } \overline{\text{Figure 15}} \\ \\ \text{ruggedness} \\ \\ \text{non-repetitive drain-source} \\ \\ \text{avalanche energy} & V_{GS} = 10 \text{ V}; \ T_{j(\text{init})} = 25 \text{ °C}; \\ \\ I_D = 37 \text{ A}; \ V_{\text{sup}} \leq 100 \text{ V}; \\ \\ \text{loo V}; \\ \\ \\ \\ \text{loo V}; \\ \\ \\ \\ \\ \\ \\ \text{loo V}; \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\$	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$\begin{array}{llllllllllllllllllllllllllllllllllll$



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain	mb	D
3	S	source		
mb	D	mounting base; connected to drain		mbb076 S
			SOT78 (TO-220AB)	

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN027-100PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	100	V
V_{DGR}	drain-gate voltage	$T_j \le 175$ °C; $T_j \ge 25$ °C; $R_{GS} = 20$ kΩ	-	100	V
V_{GS}	gate-source voltage		-20	20	V
I_D	drain current	$V_{GS} = 10 \text{ V}; T_{mb} = 100 \text{ °C}; \text{ see } \frac{\text{Figure 1}}{\text{Model}}$	-	26	Α
		$V_{GS} = 10 \text{ V}$; $T_{mb} = 25 \text{ °C}$; see Figure 1	-	37	Α
I_{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; see <u>Figure 3</u>	-	148	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	103	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
$T_{sld(M)}$	peak soldering temperature		-	260	°C
Source-dra	ain diode				
I _S	source current	T _{mb} = 25 °C	-	37	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	148	Α
Avalanche	ruggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 37 A; $V_{sup} \le$ 100 V; unclamped; R_{GS} = 50 Ω	-	59	mJ

PSMN027-100PS

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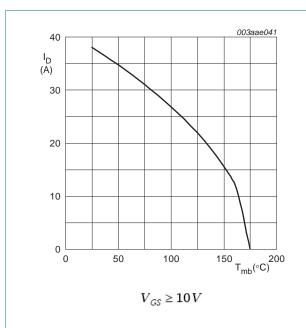


Fig 1. Continuous drain current as a function of mounting base temperature

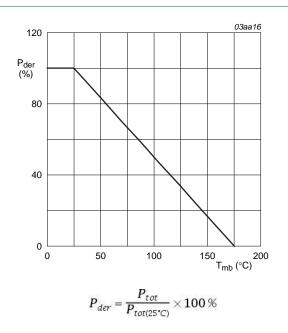
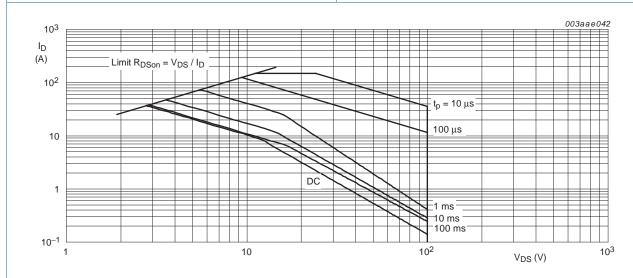


Fig 2. Normalized total power dissipation as a function of mounting base temperature



 $T_{mb} = 25 \,^{\circ}C; I_{DM}$ is single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 4	-	0.8	1.46	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	vertical in free air	-	60	-	K/W

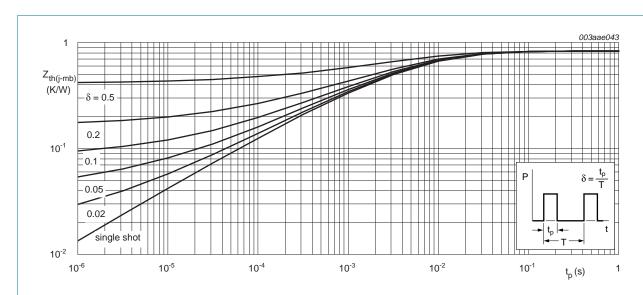


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

6. Characteristics

Table 6. Characteristics

Table 0.	Cital acteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = -55 \text{ °C}$	90	-	-	V
		$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	100	-	-	V
V _{GS(th)} gate-source threshold	gate-source threshold voltage	$I_D = 1$ mA; $V_{DS} = V_{GS}$; $T_j = 175$ °C; see Figure 10	1	-	-	V
		$I_D = 1$ mA; $V_{DS} = V_{GS}$; $T_j = 25$ °C; see <u>Figure 11</u> ; see <u>Figure 10</u>	2	3	4	V
		$I_D = 1$ mA; $V_{DS} = V_{GS}$; $T_j = -55$ °C; see Figure 10	-	-	4.8	V
I _{DSS}	drain leakage current	$V_{DS} = 100 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ °C}$	-	-	50	μΑ
		$V_{DS} = 100 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	0.08	2	μΑ
I _{GSS}	gate leakage current	$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	10	100	nΑ
		$V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	10	100	nA
R _{DSon}	R _{DSon} drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 15 \text{ A}; T_j = 100 °C;$ see <u>Figure 12</u>	-	-	48	mΩ
	$V_{GS} = 10 \text{ V}; I_D = 15 \text{ A}; T_j = 175 °C;$ see Figure 12	-	59	75	mΩ	
		$V_{GS} = 10 \text{ V}; I_D = 15 \text{ A}; T_j = 25 ^{\circ}\text{C};$ see Figure 13	-	21	26.8	mΩ
R _G	internal gate resistance (AC)	f = 1 MHz	-	0.92	-	Ω
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	$I_D = 30 \text{ A}$; $V_{DS} = 50 \text{ V}$; $V_{GS} = 10 \text{ V}$; see Figure 14; see Figure 15	-	30	-	nC
		$I_D = 0 A; V_{DS} = 0 V; V_{GS} = 10 V$	-	24	-	nC
Q_{GS}	gate-source charge	$I_D = 30 \text{ A}$; $V_{DS} = 50 \text{ V}$; $V_{GS} = 10 \text{ V}$; see Figure 14; see Figure 15	-	8	-	nC
Q _{GS(th)}	pre-threshold gate-source charge	$I_D = 30 \text{ A}; V_{DS} = 50 \text{ V}; V_{GS} = 10 \text{ V};$ see Figure 14	-	4.8	-	nC
Q _{GS(th-pl)}	post-threshold gate-source charge		-	3.4	-	nC
Q_{GD}	gate-drain charge	$I_D = 30 \text{ A}$; $V_{DS} = 50 \text{ V}$; $V_{GS} = 10 \text{ V}$; see Figure 14; see Figure 15	-	9	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	V _{DS} = 50 V; see <u>Figure 14</u> ; see <u>Figure 15</u>	-	4.9	-	V
C _{iss}	input capacitance	$V_{DS} = 50 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$	-	1624	-	pF
C _{oss}	output capacitance	T _j = 25 °C; see <u>Figure 16</u>	-	115	-	pF
C _{rss}	reverse transfer capacitance		-	74	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 50 \text{ V}; R_L = 1.7 \Omega; V_{GS} = 10 \text{ V};$	-	14.4	-	ns
t _r	rise time	$R_{G(ext)} = 4.7 \Omega; T_j = 25 °C$	-	11.4	-	ns
$t_{d(off)}$	turn-off delay time		-	29.6	-	ns
t _f	fall time		-	8.9	-	ns

Table 6. Characteristics ... continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Source-drai	in diode					
V_{SD}	source-drain voltage	$I_S = 15 \text{ A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ °C}$; see Figure 17	-	0.8	1.2	V
t _{rr}	reverse recovery time	$I_S = 10 \text{ A}$; $dI_S/dt = 100 \text{ A/}\mu\text{s}$;	-	47	-	ns
Q _r	recovered charge	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}$	-	91	-	nC

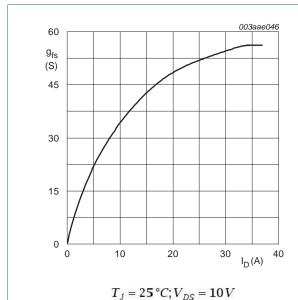


Fig 5. Forward transconductance as a function of drain current; typical values

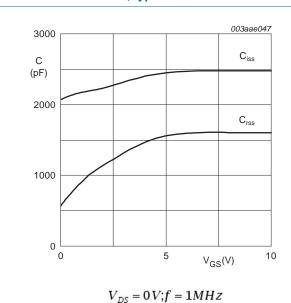
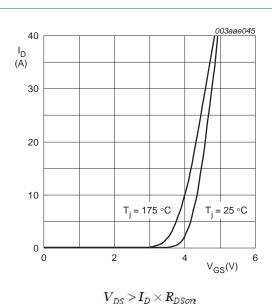
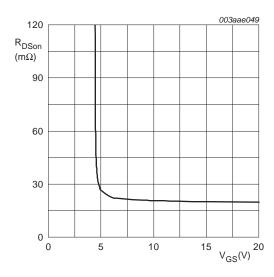


Fig 7. Input and reverse transfer capacitances as a function of gate-source voltage; typical values



 $V_{DS} > I_D \wedge R_{DSon}$

Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values



 $T_j = 25 \,{}^{\circ}C; I_D = 10A$

Fig 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

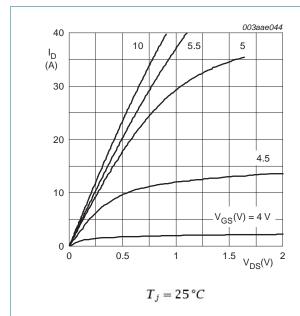


Fig 9. Output characteristics: drain current as a function of drain-source voltage; typical values

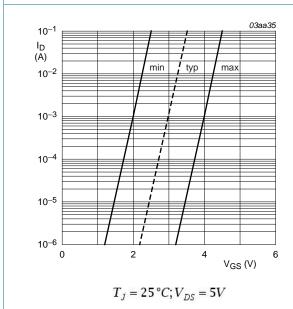


Fig 11. Sub-threshold drain current as a function of gate-source voltage

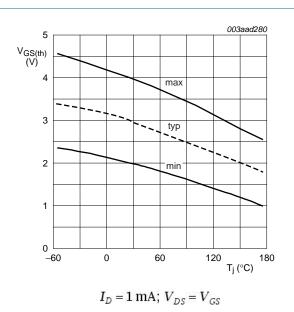


Fig 10. Gate-source threshold voltage as a function of junction temperature

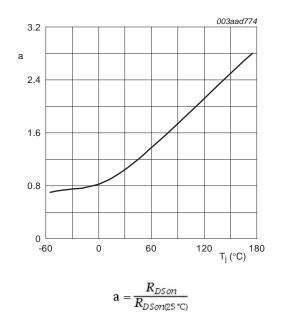


Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature

 V_{DS}

V_{GS(pl)}

V_{GS(th)}

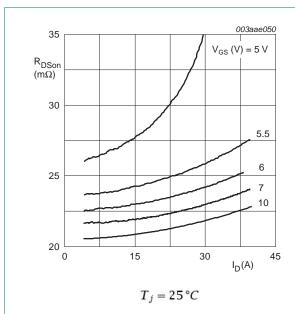


Fig 14. Gate charge waveform definitions

Q_{GS}

Q_{GD}-

003aaa508

Q_{G(tot)}

Q_{GS1}



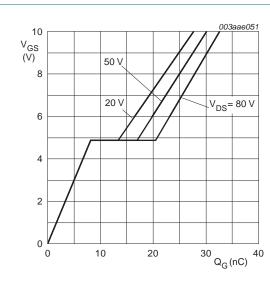


Fig 15. Gate-source voltage as a function of gate charge; typical values

 $T_j = 25 \,^{\circ}C; I_D = 30A$

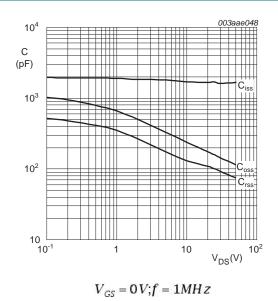


Fig 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

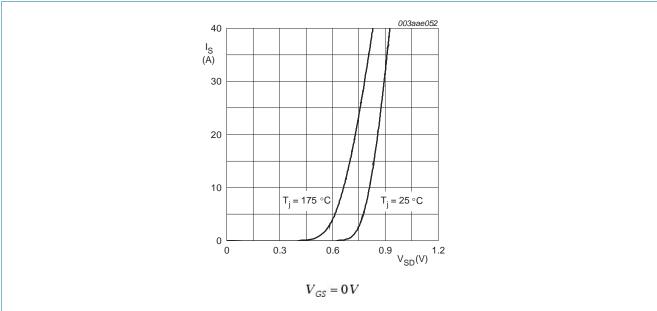
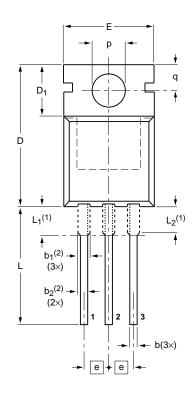
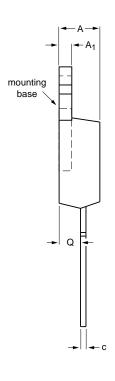


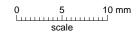
Fig 17. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

7. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB SOT78







DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	b ₁ (2)	b ₂ (2)	С	D	D ₁	E	е	L	L ₁ (1)	L ₂ ⁽¹⁾ max.	р	q	Q
mm	4.7 4.1	1.40 1.25	0.9 0.6	1.6 1.0	1.3 1.0	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2

Notes

- 1. Lead shoulder designs may vary.
- 2. Dimension includes excess dambar.

OUTLINE		REFER	NCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT78		3-lead TO-220AB	SC-46			08-04-23 08-06-13

Fig 18. Package outline SOT78 (TO-220AB)

PSMN027-100PS

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8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN027-100PS v.3	20110912	Product data sheet	-	PSMN027-100PS v.2
Modifications:	 Status changed from 	om objective to product.		
	 Various changes t 	o content.		
PSMN027-100PS v.2	20100219	Objective data sheet	-	PSMN027-100PS v.1

9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Nexperia

N-channel 100V 26.8 m Ω standard level MOSFET in TO220

11. Contents

1	Product profile
1.1	General description
1.2	Features and benefits1
1.3	Applications
1.4	Quick reference data1
2	Pinning information
3	Ordering information
4	Limiting values
5	Thermal characteristics4
6	Characteristics5
7	Package outline
8	Revision history11
9	Legal information12
9.1	Data sheet status
9.2	Definitions12
9.3	Disclaimers
9.4	Trademarks13
10	Contact information 13

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